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**DNBT8105** 

#### **1A NPN SURFACE MOUNT TRANSISTOR**

#### **Features**

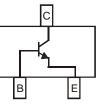
- **Epitaxial Planar Die Construction**
- Ideal for Medium Power Amplification and Switching
- High Collector Current Rating
- Complementary Version Available (DPBT8105)
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green Device" (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D •
- Terminals: Finish Matte Tin annealed over Copper leadframe. • Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram •
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



Top View



**Device Schematic** 

#### Ordering Information (Note 3)

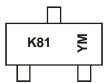
Part Number	Case	Packaging
DNBT8105-7	SOT-23	3000/Tape & Reel

No purposefully added lead. 1.

Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**

Notes:



K81 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: S = 2005)M = Month (ex: 9 = September)

Date Code Key												
Year	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	R	S	Т	U	V	W	Х	Y	Z	А	В	С
Month	Jan	Feb	Mar	Apr	Mav	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	<u>лрі</u> Л	5	6	7	R	000	000	N	
Code		2	3	4	5	0	1	0	Э	0	IN	U



# Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current - Continuous	I <sub>C</sub>	1	А
Peak Pulse Collector Current	I <sub>CM</sub>	2	A

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4) @ $T_A = 25^{\circ}C$	PD	600	mW
Thermal Resistance, Junction to Ambient (Note 4) @ $T_A = 25^{\circ}C$	$R_{ ext{ heta}JA}$	209	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	O°

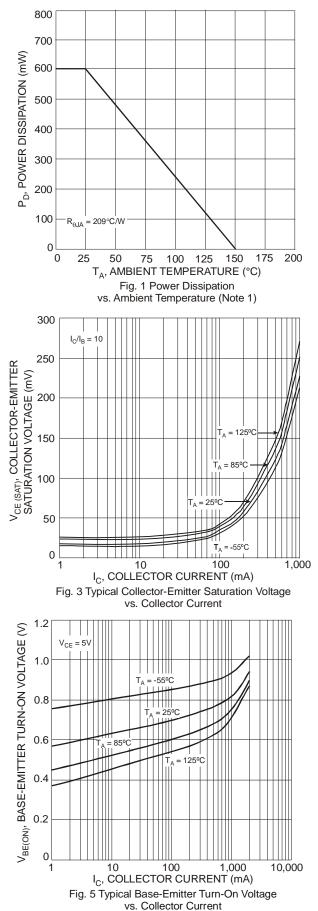
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

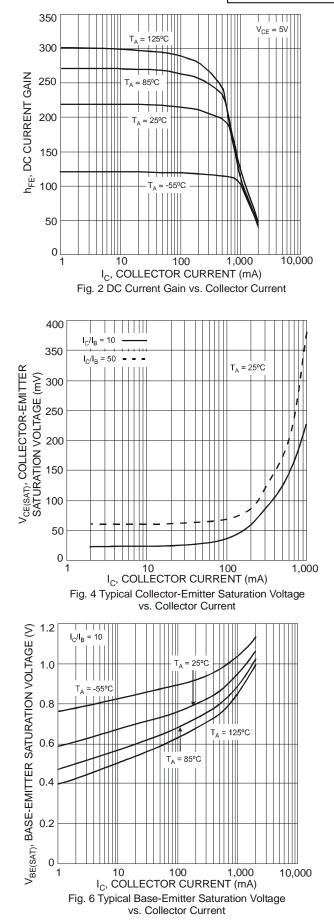
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	80		V	$I_{C} = 100 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	60	_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	5	_	V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	100	nA	$V_{CB} = 60V, I_E = 0$
Collector Cutoff Current	I <sub>CES</sub>	_	100	nA	$V_{CE} = 60V$
Emitter Cutoff Current	I <sub>EBO</sub>	_	100	nA	$V_{EB} = 4V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)					
DC Current Gain	hFE	100 100 80 30	 300 	_	$\begin{split} I_{C} &= 1 \text{mA}, \ V_{CE} = 5 \text{V} \\ I_{C} &= 500 \text{mA}, \ V_{CE} = 5 \text{V} \\ I_{C} &= 1 \text{A}, \ V_{CE} = 5 \text{V} \\ I_{C} &= 2 \text{A}, \ V_{CE} = 5 \text{V} \end{split}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		0.25 0.5	V	$I_{C} = 500$ mA, $I_{B} = 50$ mA $I_{C} = 1A$ , $I_{B} = 100$ mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>		1.1	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Base-Emitter Turn On Voltage	V <sub>BE(ON)</sub>		1.0	V	$I_{C} = 1A, V_{CE} = 5V$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	Cobo		10	pF	$V_{CB} = 10V, f = 1.0MHz$
Current Gain-Bandwidth Product	f <sub>T</sub>	150	_	MHz	$V_{CE} = 10V, I_{C} = 50mA, f = 100MHz$

 Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
Short duration pulse test used to minimize self-heating effect. Notes:

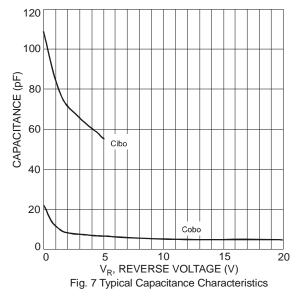




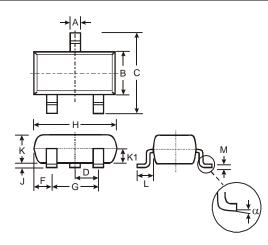






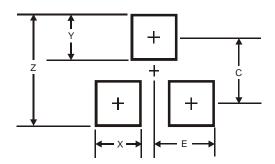


# Package Outline Dimensions



SOT-23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
К	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
М	0.085	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					

# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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